NSN 5962-01-298-2146

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View Online at https://aerobasegroup.com/nsn/5962-01-298-2146

Body Length:

Between 1.055 inches and 1.110 inches

Body Width:

Between 0.280 inches and 0.310 inches

Body Height:

Between 0.115 inches and 0.140 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Schottky and programmed and high reliability and w/clock and asynchronous and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Current Rating Per Characteristic:

185.00 milliamperes forward current, nonrepetitive, peak total value absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

5.00 input picofarads and 12.00 output picofarads

Time Rating Per Chacteristic:

65.00 nanoseconds access

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

22 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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